

Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RFL111LW, RFP121LW

Report No

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Daoud Attayi

Dates of Test

Feb. 17, June 28, Dec. 17-19, 2012 Feb. 13-14, 2013

RTS-6026-1302-07

L6ARFL110LW L6ARFP120LW

Hearing Aid Compatibility RF Emissions Test Report

Testing Lab: RIM Testing Services

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Statement of Compliance:

RIM Testing Services (RTS) declares that the product was tested in accordance with the appropriate measurement standards, guidelines and recommended practices.

This Blackberry® Smartphone is a wireless portable device and has been shown to be in compliance with FCC 20.19 (10-1-07 Edition), Hearing Aid-Compatible Mobile Handsets, FCC Public Notice DA 06-1215 (June 6, 2006) and FCC Report and Order, FCC 08-68 (Feb. 28, 2008).

Andrew Becker SAR & HAC Compliance Specialist (Verification of the Test Report) Daoud Attayi Compliance Manager (SAR/HAC) (Author of the Test report)

Masud S. Attayi Manager, Regulatory Compliance (Approval for the Test Report)

RTS is accredited according to EN ISO/IEC 17025 by:



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Annex A: Measurement plots and data

A.1 Spectrum analyser plots: CW, 80% AM and GSM/WDMA signals

A.2 Dipole validation and probe modulation factor plots

A.3 RF emission field plots

Annex B: Probe and dipole descriptions and calibration certificates

B.1 Probe and measurement chain description and specifications

B.2 Probe and dipole calibration certificates

Annex C: Test set up photos



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1.0 Introduction

This test report documents the measurement of the near electric and magnetic fields generated by a wireless communication device in the region where a hearing aid would be used. The measurement procedures of ANSI C63.19-2007 were followed along with the guidance provided by the FCC.

The electric and magnetic fields from a wireless device are scanned using a SPEAG DASY5 automated system with HAC extension and free-space probes (ER3DVx and H3DVx) in a 5cm x 5cm area, 15mm above the wireless device's acoustic output and the centre point of the probe element. The area is divided into 9 sub-grids and the maximum values of the electrical and a magnetic field scans are evaluated automatically according to the rules defined in the standard and the device is assigned a certain category. Should the wireless device's maximum T-Coil output occur in a location other than the centre of acoustic output, then the RF field scans are repeated with the measurement area centered on the maximum T-Coil output location.

The DASY5 HAC Extension consists of the following parts: the Test Arch phantom, three validation dipoles, dipole and DUT holders, magnetic and electric field probes and DASY5 software. The field probes and measurement electronics are described in Annex B.1.

The specially designed Test Arch allows high precision positioning of both the device and any of the validation dipoles. The broadband dipoles are calibrated at a single frequency and are used for system performance checks.

In order to correlate the usability of a hearing aid with a wireless device (WD), the WD's radio frequency (RF) and audio band emissions are measured. ANSI C63.19 requires:

- Radio frequency (RF) measurements of the near-field electric and magnetic fields emitted by a WD in the vicinity of the audio output to categorize these emissions for correlation with the RF immunity of the microphone mode of operation of a hearing aid.
- Audio frequency magnetic field measurements of a WD emitted in the vicinity of the audio output to categorize these emissions for correlation with the T-Coil mode of operation of a hearing aid.

Hence, the following measurements are made for the WDs:

- 1. RF E-Field emissions.
- RF H-Field emissions.
- 3. T-Coil mode, magnetic signal strength in the audio band.
- 4. T-Coil mode, magnetic signal and noise articulation index.
- 5. T-Coil mode, magnetic signal frequency response through the audio band.
- 6. RF T-Coil environment: The worst case M rating from E or H field 5x5 cm scan centered at the axial T-coil highest peak location.



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2.0 Applicable references

[1] ANSI C63.19-2007, American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.

[2] FCC 47CFR § 20.19 (10-1-07 Edition), Hearing Aid-Compatible Mobile Handsets.

[3] SPEAG DASY5 user manual, December 2012.

[4] FCC Equipment Authorization Guidance on Hearing Aid Compatibility, 285076 D01 HAC Guidance v03, August, 2012.

[5] FCC Report and Order, DA 12-550, April 2012.



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3.0 Equipment unit tested

3.1 Picture of device

Please refer to Annex C.

Figure 1. BlackBerry® smartphone

3.2 Device description

Device Model	RFL111LW					
FCC ID	L6ARFL110LW	L6ARFL110LW				
	Radiated: 25CF0A	D9 (Rev 2), 2668C7	1D (Rev 3)			
PIN	Conducted: 25CF0	ADB (Rev 2), 2668C	70C (Rev 3)			
Hardware Rev	Rev2-905-00/01, Re	ev3-906-01/03/04				
Software Version	127.0.1.2982/3123/3	3454/3901, MFI_4_0	_10-180/181			
Prototype or Production Unit	Production					
	1-slot	2-slots	3-slots	4-slots		
Mada(a) of One andian	GSM 850	EDGE/GPRS	EDGE/GPRS	EDGE/GPRS		
Mode(s) of Operation Nominal Maximum conducted	GSM 1900	850/1900	850/1900	850/1900		
RF Output Power (dBm)	33.5 29.0	30.0 28.5	29.0 26.0	27.5 25.0		
Tolerance in Power Setting on						
centre channel (dB)	± 0.5	± 0.5	± 0.5	± 0.5		
Duty Cycle	1:8	2:8	3:8	4:8		
Transmitting Frequency Range	824.2 – 848.8	824.2 – 848.8	824.2 – 848.8	824.2 – 848.8		
(MHz)	1850.2 - 1909.8	1850.2 - 1909.8	1850.2 - 1909.8	1850.2 – 1909.8		
	HSPA ⁺	HSPA ⁺				
Mada(a) at One notice	WCDMA/UMTS WCDMA/UMTS 802.11b 802.					
Mode(s) of Operation Nominal Maximum conducted	FDD V (850)	FDD II (1900)				
RF Output Power (dBm)	24.5	22.5	19.0	18.5		
Tolerance in Power Setting on						
centre channel (dB)	± 0.5	± 0.5	± 0.5	± 0.5		
Duty Cycle	1:1	1:1	1:1	1:1		
Transmitting Frequency Range (MHz)	824.6 – 846.6	1852.4 – 1907.6	2412-2462	2412-2462		
Mode(s) of Operation	802.11n	802.11a/n (low band)	802.11a/n (middle band)	802.11a/n (upper band I)		
Nominal Maximum conducted RF Output Power (dBm)	16.0	13.0	14.5	16.5		
Tolerance in Power Setting on	. 0.5	. 0.5	. 0.5	. 0.5		
centre channel (dB)	± 0.5	± 0.5	± 0.5	± 0.5		
Duty Cycle	1:1	1:1	1:1	1:1		
Transmitting Frequency Range (MHz)	2412-2462	5180-5240	5260-5320	5500-5700		
Mode(s) of Operation	802.11a/n (upper band II)	Bluetooth	NFC			
Nominal Maximum conducted RF Output Power (dBm)	11.5	10.0	N/A			



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Tolerance in Power Setting on centre channel (dB)	± 0.5	N/A	N/A	
Duty Cycle	1:1	N/A	N/A	
Transmitting Frequency Range (MHz)	5749-5825	2402-2483	13.56	

Table 3.1.a Test device characterization non-LTE U.S. wireless operating modes/bands

Device Model	RFP121LW						
FCC ID	L6ARFP120LW						
	Radiated: 2641D6A8 (Rev 1), 26703205 (Rev 2)						
PIN		663 (Rev 1), 267031F0	C(Rev 2)				
Hardware Rev	Rev1-905-00/01, Re						
Software Version	127.0.1.3427/3901,	MFI_4_0_10-180/18	1				
Prototype or Production Unit	Production						
Mode(s) of Operation	1-slot GSM 850 GSM 1900	2-slots EDGE/GPRS 850/1900	3-slots EDGE/GPRS 850/1900	4-slots EDGE/GPRS 850/1900			
Nominal Maximum conducted RF Output Power (dBm)	33.5 29.0	30.0 28.5	29.0 26.0	27.5 25.0			
Tolerance in Power Setting on centre channel (dB)	± 0.5	± 0.5	± 0.5	± 0.5			
Duty Cycle	1:8	2:8	3:8	4:8			
Transmitting Frequency Range (MHz)	824.2 – 848.8 1850.2 – 1909.8	824.2 – 848.8 1850.2 – 1909.8	824.2 – 848.8 1850.2 – 1909.8	824.2 – 848.8 1850.2 – 1909.8			
Mode(s) of Operation	HSPA ⁺ WCDMA / UMTS FDD V (850)	HSPA ⁺ WCDMA / UMTS FDD II (1900)	HSPA+ WCDMA / UMTS FDD IV (1700)	802.11b			
Nominal Maximum conducted RF Output Power (dBm)	24.5	22.5	22.0	19.0			
Tolerance in Power Setting on centre channel (dB)	± 0.5	± 0.5	± 0.5	± 0.5			
Duty Cycle	1:1	1:1	1:1	1:1			
Transmitting Frequency Range (MHz)	824.6 – 846.6						
Mode(s) of Operation	802.11g	802.11n	802.11a/n (low band)	802.11a/n (middle band)			
Nominal Maximum conducted RF Output Power (dBm)	18.5	16.0	13.0	14.5			
Tolerance in Power Setting on centre channel (dB)	± 0.5	± 0.5	± 0.5	± 0.5			
Duty Cycle	1:1	1:1	1:1	1:1			
Transmitting Frequency Range (MHz)	2412-2462	2412-2462	5180-5240	5260-5320			
Mode(s) of Operation	802.11a/n (upper band I)	802.11a/n (upper band II)	Bluetooth	NFC			
Nominal Maximum conducted RF Output Power (dBm)	16.5	11.50	10.0	N/A			
Tolerance in Power Setting on centre channel (dB)	± 0.5	± 0.5	N/A	N/A			

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Duty Cycle	1:1	1:1	N/A	N/A
Transmitting Frequency Range (MHz)	5500-5700	5749-5825	2402-2483	13.56

Table 3.1.b Test device characterization non-LTE U.S. wireless operating modes/bands

Note 1: BlackBerry model: RFP121LW supports additional RF band: HSPA+/WCDMA/UMTS band IV and some other minor changes.

Please refer to the manufacturer's hardware similarity declaration document for the two models: RFL111LW and RFP121LW.

Device Model		RFL111LW				
FCC ID		L6ARFL110LW	L6ARFL110LW			
		Radiated: 25CF0AD9 (Rev 2), 2668C71D (Rev 3)				
PIN		Conducted: 250	CF0ADB (Rev 2)), 2668C70C (Rev 3)		
Hardware Rev		Rev2-905-00/01,		.,		
Software Version				IFI 4 0 10-180/181		
Prototype or Production	ı Unit	Production				
. retetype or r reduction	. •	Band 17: 5 MHz, 10	MHz			
		Band 5: 1.4 MHz, 3		Hz		
Transmission channel bandw	idth	Band 4: 1.4 MHz, 3	MHz, 5 MHz, 10 M	Hz, 15 MHz, 20 MHz		
BW			MHz, 5 MHz, 10 M	Hz, 15 MHz, 20 MHz		
Transmission channel number	r and free	quencies				
	LTE ba	nd 17		LTE band 5		
	Chan.	na 17	f (MHz)	Chan.	f (MHz)	
L*	23780		709	20450	829	
M	23790		710	20525	836.5	
H*	23800		711	20600	844.0	
	LTE ba	nd 4		LTE band 2		
	Chan.		f (MHz)	Chan.	f (MHz)	
L*	20050		1720	18700	1860	
M	20175		1732.5	18900	1880	
H*	20300		1745	19100	1900	
TIE C. A.		G . 2				
UE Category Modulation supported in upli	inl.	Category 3 QPSK, 16QAM				
Description of LTE antenna	ШК	1 Tx/Rx Ant, Sharing	a with GSM/HMTS:	1 Ry Divercity		
LTE voice available/supporte	-d	VoIP Third party ap		1 KX Diversity		
Hotspot with LTE+WiFi	<u> </u>	Yes Yes	pheation possible			
Hotspot with LTE+WiFi activ	ve with					
GSM//WCDMA voice		No				
LTE MPR permanently built	-in by					
design		Yes				
LTE A-MPR			testing, by setting	NV value to NV_01 on the Cl	MW500	
		Band 17: 23.7 dBm				
		Band 5: 23.78 dBm				
Band 4: 23.83 dBm						
LTE maximum average power (dBm) Band 2: 22.34 dBm						

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Other non-LTE U.S. wireless operating modes/bands	GSM//WCDMA/HSPA+	835 MHz GSM 1900 MHz GSM 835 MHz WCDMA band V 1900 MHz WCDMA band II
	WiFi and BT	2.4 GHz Wi-Fi
		5 GHz Wi-Fi 2.4 GHz BT
Simultaneous Tx conditions	N/A for HAC	
Power reduction applied for		
SAR/HAC compliance	No	

Table 3.2.a Test device characterization all U.S. wireless operating modes/bands

Device Model		RFP121LW				
FCC ID		L6ARFP120LW				
		Radiated: 2641I	Radiated: 2641D6A8 (Rev 1), 26703205 (Rev 2)			
PIN			1D663 (Rev 1), 26	, ,		
Hardware Rev			Rev2-906-00/01	, ,		
Software Version		,	01, MFI 4 0 10-1	80/181		
Prototype or Production	n Unit	Production	,			
		Band 17: 5 MHz, 10) MHz			
		Band 5: 1.4 MHz, 3	MHz, 5 MHz, 10 MHz	Z		
Transmission channel bandw	idth	Band 4: 1.4 MHz, 3	MHz, 5 MHz, 10 MHz	, 15 MHz, 20 MHz		
BW			MHz, 5 MHz, 10 MHz	, 15 MHz, 20 MHz		
Transmission channel number	er and freq	uencies				
	LTE bar	ad 17		LTE band 5		
	Chan.	IU 17	f (MHz)	Chan.	f (MHz)	
L*	23780		709	20450	829	
M	23790		710	20525	836.5	
H*	23800		711	20600	844.0	
				1		
	LTE bar	nd 4		LTE band 2		
	Chan.		f (MHz)	Chan.	f (MHz)	
L*	20050		1720	18700	1860	
M	20175		1732.5	18900	1880	
H*	20300		1745	19100	1900	
UE Category		Category 3				
Modulation supported in upl	ink	OPSK, 16OAM				
Description of LTE antenna	11114	, ,	g with GSM/UMTS; 1	Rx Diversity		
LTE voice available/supported VoIP_Third party application possible			/	20. 21. 51511		
Hotspot with LTE+WiFi	Yes					
Hotspot with LTE+WiFi acti	ve with					
GSM//WCDMA voice		No				
LTE MPR permanently built	lt-in by					
design		Yes				
LTE A-MPR		Disabled during SAF	R testing, by setting N	V value to NV_01 on the CMW	7500	

	sting vices™				
Author Data Dates of Test Repor		Report No	FCC ID)	
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	D 117 007 ID			
	Band 17: 23.7 dBm			
	Band 5: 23.78 dBm			
	Band 4: 23.83 dBm			
LTE maximum average power (dBm)	Band 2: 22.34 dBm			
Other non-LTE U.S. wireless operating modes/bands	GSM//WCDMA/HSPA+	835 MHz GSM 1900 MHz GSM 835 MHz WCDMA band V 1700 MHz WCDMA band IV 1900 MHz WCDMA band II		
	WiFi and BT	2.4 GHz Wi-Fi 5 GHz Wi-Fi		
		2.4 GHz BT		
Simultaneous Tx conditions	N/A for HAC			
Power reduction applied for				
SAR/HAC compliance	No			

Table 3.2.b Test device characterization all U.S. wireless operating modes/bands

Note 2: BT and NFC are not activated during test because it is not held-to-ear service.

Note 3: Wi-Fi and LTE are not activated during test because ANSI C63.19-2007standard does not cover these technologies.



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3.3 Battery

- 1) BAT-49702-00x (1800 mAh)
- 2) BAT-52961-002 (2100 mAh)

3.4 Antenna description

Туре	Internal fixed antenna
	Bottom back centre (main
Location	licensed transmitter)
Configuration	Internal fixed antenna

Table 3.3. Antenna description

4.0 List of test equipment

Manufacturer	Test Equipment	Model Number	Serial Number	Calibration Due Date (MM/DD/YY)
SCHMID & Partner Engineering AG	Data Acquisition Electronics (DAE3)	DAE3 V1	473	01/13/2013 *
SCHMID & Partner Engineering AG	Data Acquisition Electronics (DAE3)	DAE3 V1	472	03/07/2013
SCHMID & Partner Engineering AG	3-Dimensional E-Field Probe for Near-Field	ER3DV6	2286	01/11/2014
SCHMID & Partner Engineering AG	3-Dimensional H-Field Probe for Near-Field	H3DV6	6105	11/09/2013
Rohde & Schwarz	Base Station Simulator	CMU200	109747	11/19/2013
Rohde & Schwarz	Spectrum Analyzer	ESP 30	100884	12/02/2013
Agilent Technologies	Signal generator	8648C	4037U03155	09/23/2013
Agilent Technologies	Power meter	E4419B	GB40202821	09/23/2013
Agilent Technologies	Power sensor	8481A	MY41095417	09/26/2013
Agilent Technologies	Power meter	N1911A	MY45100905	05/17/2013
Agilent Technologies	Power sensor	N1921A	SG45240281	06/12/2013
Amplifier Research	Amplifier	5S1G4M3	300986	CNR
SCHMID & Partner Engineering AG	Validation Dipole	CD835V3	1011	11/08/2013
SCHMID & Partner Engineering AG	Validation Dipole	CD1880V3	1008	11/08/2013

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Table 4.1. List of test equipment

5.0 Measurement procedures

5.1 System Validation

The test setup should be validated when first configured and verified periodically thereafter to ensure proper function. The procedure consists of two parts: dipole validation and determination of probe modulation factor.

5.1.1 Dipole Validation

The HAC validation dipole antenna serves as a known source for an electrical and magnetic RF output.

- 1. The dipole antenna was placed in the position normally occupied by the WD.
- 2. The dipole was energized with a 20 dBm un-modulated continuous-wave signal.
- 3. The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements.
- 4. The length of the dipole was scanned with both E-field and H-field probes and the maximum value for each scan was recorded.
- 5. The readings were compared with the values provided by the probe manufacturer and were found to agree within tolerance of +/- 10%. Please refer to Annex A.2 for Dipole Validation Plots.

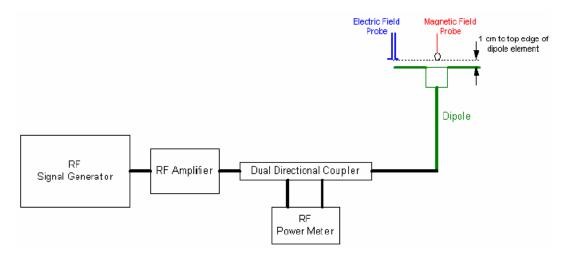


Figure 5.1: Dipole validation procedure

^{*} This equipment was sent out for calibration before due date.



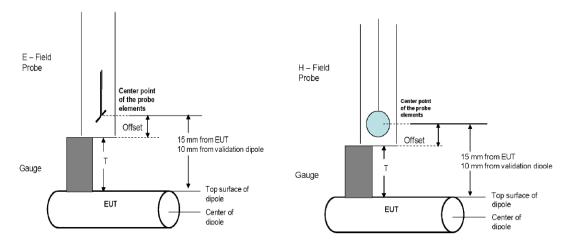


Figure 5.2: Gauge Block with E-Field & H-Field probes

5.1.2 RF Field Probe Modulation Factor

The Probe Modulation Factor (PMF) characterizes the responses of the E-field and H-field probes and their instrumentation chain to a modulated signal. The PMF is the ratio of the responses to fields produced by CW and modulated signals having equal peak amplitude.

Three test cases are recommended. The real or emulated WD (Wireless device) modulated signal, an unmodulated (CW) and an 80% AM RF signal shall be used for each relevant frequency band. Each of the test cases below shall be measured with both E_ and H_Field probe.

a) Measurement of real and emulated signal

- Set a WD or emulated signal source to apply full power into the reference dipole.
- Measure both the peak and average input power applied to the antenna and record the values using the following test instructions for measuring the RF interference of a modulated signal.
 Spectrum analyzer set up:

RBW ≥ emission bandwidth

Video Bandwidth ≥ 20 KHz

Span: Zero

Center Frequency: Nominal center of frequency channel

Amplitude: Linear (logarithmic scale may be used)

Detection: Peak detection Trigger: Video or IF trigger

Sweep rate: sufficiently rapid to permit the complete pulse to be resolved accurately.



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 Using near-field measurement system, scan the antenna over the appropriately sized area and record the greatest average power reading observed.

b) Measurement of CW and AM

- Set the RF signal generator for CW or 80 % AM and set the output power so the peak power applied to the antenna is equal to that recorded for the real or emulated signal using the WD modulation format.
- Measure both the peak and average input power applied to the antenna and record these values. Calculate the peak to average power ratio (PAR). The PAR for the CW signal should be 0.0 dB and 3.9 dB for the AM signal with 80% modulation depth from each other and the peak should be that amount above the target values.

The PMF was calculated for the following signals: 80% AM and the modulated signal produced by the WD. The PMF measurement was performed with the field probe and instrumentation that will be used together during RF emissions measurements. Once calculated, the PMF was entered into the DASY5 software and applied to the measured modulated fields of the specified type.

ANSI C63.19 outlines the following alternate procedure as one method for determining probe modulation factor:

- 1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
- 2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
- 3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna.
- 4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
- 5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
- 6. Record the reading of the probe measurement system of the unmodulated signal.
- 7. The ratio, in linear units, of the probe reading in step 6 to the reading in step 3 is the E-field modulation factor.
- 8. Repeat the above using the H-field probe, except locate the probe at the center of the dipole.

Please refer to Annex A.1 for 0 Hz-span spectrum analyzer plots. The signal generator was used to generate the CW and AM signals. The WD was used to generate the modulated signal.

Please refer to Annex A.2 for probe modulation factor measurement plots.



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f (MHz)	Signal Type	Peak Power (dBm)	Measured E-Field (V/m)	Target E-Field (V/m)	Delta (%)	PMF
835	CW (Validation)	20.00	168.4	159.7	+5.45	
835	GSM 850	20.47	54.25			3.00
835	CW	20.49	162.8			
835	80 % AM	20.52	102.0			
835	WCDMA band V	12.59	64.41			1.07
835	CW	12.60	68.64			
835	80 % AM	12.59	45.21			
1880	CW (Validation)	20.00	124.4	135.3	-8.10	
1880	CW (Validation)	20.00	128.6	135.3	-4.95	
1880	GSM 1900	16.78	29.81			2.85
1880	CW	16.80	84.89			
1880	80 % AM	16.77	53.60			
1880	WCDMA band II	10.60	42.43			1.00
1880	CW	10.61	42.41			
1880	80 % AM	10.63	27.40			
£						
f		Peak	Measured	Target	Delta	
f (MHz)	Signal Type	Power	H-Field	H-Field	Delta	PMF
(MHz)		Power (dBm)	H-Field (A/m)	H-Field (A/m)	(%)	PMF
(MHz) 835	CW (Validation)	Power (dBm) 20.00	H-Field (A/m) 0.444	H-Field		
(MHz) 835 835	CW (Validation) GSM 850	Power (dBm) 20.00 20.47	H-Field (A/m) 0.444 0.163	H-Field (A/m)	(%)	PMF 2.89
(MHz) 835 835 835	CW (Validation) GSM 850 CW	Power (dBm) 20.00 20.47 20.49	H-Field (A/m) 0.444 0.163 0.471	H-Field (A/m)	(%)	
835 835 835 835 835	CW (Validation) GSM 850 CW 80 % AM	Power (dBm) 20.00 20.47 20.49 20.52	H-Field (A/m) 0.444 0.163 0.471 0.304	H-Field (A/m)	(%)	2.89
835 835 835 835 835 835	CW (Validation) GSM 850 CW 80 % AM WCDMA band V	Power (dBm) 20.00 20.47 20.49 20.52 12.59	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181	H-Field (A/m)	(%)	
835 835 835 835 835 835 835	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197	H-Field (A/m)	(%)	2.89
835 835 835 835 835 835	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM	Power (dBm) 20.00 20.47 20.49 20.52 12.59	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181	H-Field (A/m)	(%)	2.89
835 835 835 835 835 835 835	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM CW (Validation)	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197	H-Field (A/m)	(%)	2.89
835 835 835 835 835 835 835 835	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60 12.59	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197 0.127	H-Field (A/m) 0.462	-3.90	2.89
(MHz) 835 835 835 835 835 835 835 83	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM CW (Validation)	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60 12.59 20.00	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197 0.127 0.444	H-Field (A/m) 0.462 0.456	-2.63	2.89
(MHz) 835 835 835 835 835 835 835 1880 1880	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM CW (Validation) CW (Validation) GSM 1900 CW	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60 12.59 20.00 20.00	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197 0.127 0.444 0.446	H-Field (A/m) 0.462 0.456	-2.63	2.89
(MHz) 835 835 835 835 835 835 835 1880 1880 1880 1880	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM CW (Validation) CW (Validation) GSM 1900 CW 80 % AM	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60 12.59 20.00 20.00 16.78 16.80 16.77	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197 0.127 0.444 0.446 0.105 0.300 0.194	H-Field (A/m) 0.462 0.456	-2.63	2.89
835 835 835 835 835 835 835 835 835 1880 1880 1880 1880	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM CW (Validation) CW (Validation) GSM 1900 CW 80 % AM WCDMA band II	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60 12.59 20.00 20.00 16.78 16.80 16.77 10.60	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197 0.127 0.444 0.446 0.105 0.300 0.194 0.150	H-Field (A/m) 0.462 0.456	-2.63	2.89
(MHz) 835 835 835 835 835 835 835 1880 1880 1880 1880	CW (Validation) GSM 850 CW 80 % AM WCDMA band V CW 80 % AM CW (Validation) CW (Validation) GSM 1900 CW 80 % AM	Power (dBm) 20.00 20.47 20.49 20.52 12.59 12.60 12.59 20.00 20.00 16.78 16.80 16.77	H-Field (A/m) 0.444 0.163 0.471 0.304 0.181 0.197 0.127 0.444 0.446 0.105 0.300 0.194	H-Field (A/m) 0.462 0.456	-2.63	2.89

Table 5.1: Dipole Validation and Modulation Factors

Probe Modulation Factor = Measured E or H-Field (CW)/Measured E or H-Field (Modulated)



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5.2 Near-Field RF Emission

The following procedure was used to measure RF near E-field and H-field emissions:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. The WD was oriented in its intended test position with the reference plane in the horizontal plane and was secured in the device holder to maintain position accuracy.
- 3. A CMU 200 Base Station Simulator was used to place a normal voice call to the WD on the desired channel and to transmit at maximum power.
- 4. The DASY5 system measures power drift as part of each scan. If the power during a scan drifted by more than 0.20 dB, the scan was repeated. Power drift measurements for the worst-case scans are included in Annex A.3. A fully charged battery was used for each test.
- 5. The 5cm x 5cm measurement grid was centered on the center of the acoustic output or the T-Coil output, as appropriate. The field probe was located at the initial position at the center of the measurement grid.
- 6. A surface verification was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane.
- 7. The electric field probe, and separately the magnetic field probe, was used to measure the highest field strength in the 5cm x 5cm reference plane. The center point of the probe measurement element(s) shall be held 15 mm from the WD reference plane.
- 8. The entire 5cm x 5cm region was scanned with a 5mm step size. The reading was recorded at each measurement location. Justification of the step size and interpolation used is provided at the end of Annex A.2.
- 9. Around the center sub-grid, five contiguous sub-grids were identified with the lowest maximum field strength readings. Please note that a maximum of five sub-grids can be excluded for both E-and H-field measurements.
- 10. The highest field reading was identified within the non-excluded sub-grids
- 11. The highest field reading was converted from average to peak V/m or A/m, as appropriate. This conversion was done by the DASY5 SEMCAD processor after entering correct PMF.
- 12. Once the worst-case configuration was determined, the WD was tested with second source battery.
- 13. The highest peak reading was compared to the categories defined in C63.19 using the appropriate AWF.
- If a WD has more than one antenna position, it is necessary to test the WD only in the condition of maximum antenna efficiency, i.e. antenna extended.
- The WD's backlight shuts off automatically a short time after a call is established.



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Category	Telephone RF Parameters < 960 MHz					
Near Field	AWF	E-Field Emis	sions	H-Field Emis	sions	
Category M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m	
	-5	473.2 to 841.4	V/m	1.43 to 2.54	A/m	
Category M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m	
	-5	266.1 to 473.2	V/m	0.80 to 1.43	A/m	
Category M3/T3	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m	
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m	
Category M4/T4	4 0 < 199.5		V/m	< 0.60	A/m	
	-5	< 149.6	V/m	< 0.45	A/m	

Category	Telephone RF Parameters > 960 MHz					
Near Field	AWF	E-Field Emis	E-Field Emissions		sions	
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m	
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m	
Category M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m	
	-5	84.1 to 149.6	V/m	0.25 to 0.45	A/m	
Category M3/T3	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m	
	-5	47.3 to 84.1	V/m	0.14 to 0.25	A/m	
Category M4/T4	0	<63.1	V/m	<0.19	A/m	
	-5	<47.3	V/m	<0.14	A/m	

Table 5.2: Wireless Device near-field categories

Standard	Technology	AWF (dB)
TIA/EIA/IS-2000	CDMA	0
TIA/EIA-136	TDMA (50 Hz)	0
J-STD-007	GSM (217)	-5
T1/T1P1/3GPP	UMTS (WCDMA)	0
iDEN TM	TDMA (22 and 11 Hz)	0

Table 5.3: Articulation Weighting Factor (AWF)

Tes Serv	Testing Services Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RFL111LW, RFP121LW		
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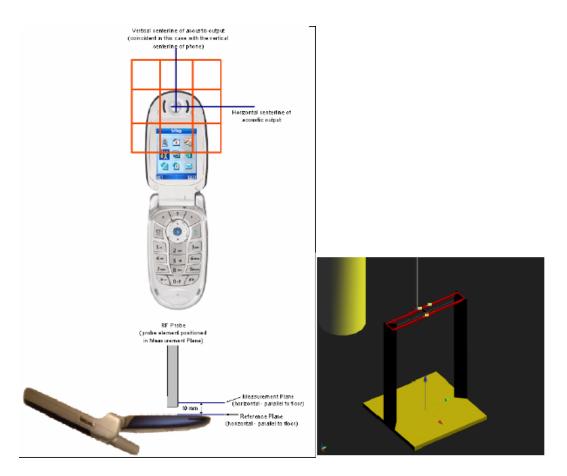


Figure 5.3: WD reference plane for RF emission measurements Figure 5.4: HAC Phantom/Test Arch



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6.0 Summary of results

	RF Emissions Test						
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak E-Field (V/m)	Center of Speaker or Telecoil	M- Rating		
	824.2	33.9	226.1	Speaker	3		
GSM 850	836.8	33.9	230.7	Speaker	3		
GSM 930	848.8	33.6	212.9	Speaker	3		
	836.8	33.9	217.7	Telecoil	3		
WCDMA	826.4	24.7	66.0	Speaker	4		
band V	836.4	24.5	72.8	Speaker	4		
850	846.6	24.4	82.9	Speaker	4		
	1850.2	28.9	75.5	Speaker	3		
GSM	1880.0	29.1	72.7	Speaker	3		
1900	1909.8	28.8	71.8	Speaker	3		
	1850.2	28.9	75.9	Telecoil	3		
WCDMA	1852.4	22.9	30.6	Speaker	4		
band II 1900	1880.0	22.8	32.0	Speaker	4		
	1907.6	22.8	31.3	Speaker	4		
	Ove	rall M-Ra	ting:		3		

Table 6.1-E-Field Data Summary (1800 mAh battery), model: RFL111LW

RF Emissions Test						
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak H- Field (A/m)	Center of Speaker or Telecoil	M- Rating	
	1850.2	28.9	77.9	Telecoil	3	
GSM 1900	1880.0					
	1909.8					

Table 6.2-E-Field Data Summary (2100 mAh battery), model: RFL111LW



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		RF Emi	ssions Test				
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak E-Field (V/m)	Center of Speaker or Telecoil	M- Rating		
	824.2	33.9	187.0	speaker	3		
GSM 850	836.8	33.9	203.9	speaker	3		
GSIM 930	848.8	33.6	184.7	speaker	3		
	836.8	33.9	193.0	telecoil	3		
WCDMA	826.4	24.7	74.3	speaker	4		
band V	836.4	24.5	76.9	speaker	4		
850	846.6	24.4	80.5	speaker	4		
WCDMA	1712.4	22.4	35.6	speaker	4		
band IV	1732.6	22.3	36.0	speaker	4		
1800	1752.6	22.5	36.0	speaker	4		
	1850.2	29.5	64.02	speaker	3		
GSM	1880.0	29.6	57.87	speaker	3		
1900	1909.8	29.3	62.02	speaker	3		
	1850.2	29.5	66.89	telecoil	3		
WCDMA	1852.4	22.9	31.2	speaker	4		
band II 1900	1880.0	22.8	30.5	speaker	4		
	1907.6	22.8	29.6	speaker	4		
	Overall M-Rating:						

Table 6.3-E-Field Data Summary (1800 mAh battery), model: RFP121LW

	RF Emissions Test						
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak E-Field (V/m)	Center of Speaker or Telecoil	M- Rating		
CCM							
GSM 1900							
1700	1850.2	29.5	68.07	telecoil	3		

Table 6.4-E-Field Data Summary (2100 mAh battery), model: RFP121LW



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	RF Emissions Test						
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak H- Field (A/m)	Center of Speaker or Telecoil	M- Rating		
	824.2	33.9	0.49	Speaker	3		
GSM 850	836.8	33.9	0.52	Speaker	3		
GSWI 650	848.8	33.6	0.51	Speaker	3		
	848.8	33.6	0.56	Telecoil	3		
WCDMA	826.4	24.7	0.15	Speaker	4		
band V	836.4	24.5	0.17	Speaker	4		
850	846.6	24.4	0.19	Speaker	4		
	1850.2	28.9	0.22	Speaker	3		
GSM 1900	1880.0	29.1	0.21	Speaker	3		
GSW 1900	1909.8	28.8	0.21	Speaker	3		
	1850.2	28.9	0.22	Telecoil	3		
WCDMA	1852.4	22.9	0.09	Speaker	4		
band II	1880.0	22.8	0.09	Speaker	4		
1900	1907.6	22.8	0.09	Speaker	4		
	Ove	erall M-R	ating:		3		

Table 6.5- H--Field Data Summary (1800 mAh battery), model: RFL111LW

RF Emissions Test						
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak H- Field (A/m)	Center of Speaker or Telecoil	M- Rating	
	1850.2	28.9	0.22	Telecoil	3	
GSM 1900	1880.0					
	1909.8					

Table 6.6- H--Field Data Summary (2100 mAh battery), model: RFL111LW



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RF Emissions Test							
Mode	f (MHz)	Cond. Peak Pwr. H- Field (dBm) (A/m)		Center of Speaker or Telecoil	M- Rating		
GSM 850	824.2	33.9	0.42	Speaker	4		
	836.8	33.9	0.44	Speaker	4		
	848.8	33.6	0.43	Speaker	4		
	848.8	33.9	0.49	Telecoil	4		
WCDMA	826.4	24.7	0.16	Speaker	4		
band V	836.4	24.5	0.17	Speaker	4		
850	846.6	24.4	0.18	Speaker	4		
WCDMA	1712.4	22.4	0.10	speaker	4		
band IV	1732.6	22.3	0.10	speaker	4		
1800	1752.6	22.5	0.10	speaker	4		
GSM 1900	1850.2	29.5	0.181	speaker	3		
	1880.0	29.6	0.166	speaker	3		
	1909.8	29.3	0.152	speaker	3		
	1850.2	29.5	0.194	telecoil	3		
WCDMA band II 1900	1852.4	22.9	0.09	Speaker	4		
	1880.0	22.8	0.10	Speaker	4		
	1907.6	22.8	0.09	Speaker	4		
Overall M-Rating:							

Table 6.7- H--Field Data Summary (1800 mAh battery), model: RFP121LW

RF Emissions Test							
Mode	f (MHz)	Cond. Pwr. (dBm)	Peak E-Field (V/m)	Center of Speaker or Telecoil	M- Rating		
GSM 1900	1850.2	29.5	0.195	telecoil	3		

Table 6.8– H--Field Data Summary (21000 mAh battery), model: RFP121LW



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6.1 Conclusion

The BlackBerry® Smartphone Model: **RFL111LW**, **RFP121LW** are categorized to be **M3T4** based on HAC RF Emission and ABM T-Coil performance in accordance with ANSI C63.19-2007: American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.

Therefore, the device is found to be in compliance with the requirements of FCC 20.19 (10-1-07 Edition) Hearing Aid-Compatible Mobile Handsets and FCC Report and Order, DA 12-550 (April, 2012).



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7.0 Measurement uncertainty

HAC Uncertainty Budget According to ANSI C63.19 [1]							
	Uncertainty	Prob.	Div.	(c_i)	(c_i)	Std. Unc.	Std. Unc.
Error Description	value	Dist.		Е	Н	Е	Н
Measurement System Probe Calibration	$\pm 5.1 \%$	N	1	1	1	±5.1 %	15 107
			1	_	1		±5.1 %
Axial Isotropy	$\pm 4.7 \%$	R	$\sqrt{3}$	1	1	±2.7 %	$\pm 2.7 \%$
Sensor Displacement	$\pm 16.5\%$	R	$\sqrt{3}$	1	0.145	$\pm 9.5\%$	$\pm 1.4\%$
Boundary Effects	$\pm 2.4\%$	R	$\sqrt{3}$	1	1	$\pm 1.4\%$	$\pm 1.4\%$
Linearity	$\pm 4.7\%$	R	$\sqrt{3}$	1	1	$\pm 2.7\%$	$\pm 2.7\%$
Scaling to Peak Envelope Power	$\pm 2.0\%$	R	$\sqrt{3}$	1	1	$\pm 1.2\%$	$\pm 1.2\%$
System Detection Limit	$\pm 1.0\%$	R	$\sqrt{3}$	1	1	$\pm 0.6\%$	$\pm 0.6\%$
Readout Electronics	$\pm 0.3\%$	N	1	1	1	$\pm 0.3\%$	$\pm 0.3\%$
Response Time	$\pm 0.8\%$	R	$\sqrt{3}$	1	1	$\pm 0.5\%$	$\pm 0.5\%$
Integration Time	$\pm 2.6\%$	R	$\sqrt{3}$	1	1	$\pm 1.5\%$	$\pm 1.5\%$
RF Ambient Conditions	$\pm 3.0\%$	R	$\sqrt{3}$	1	1	$\pm 1.7 \%$	$\pm 1.7\%$
RF Reflections	$\pm 12.0\%$	R	$\sqrt{3}$	1	1	$\pm 6.9\%$	$\pm 6.9\%$
Probe Positioner	$\pm 1.2\%$	R	$\sqrt{3}$	1	0.67	$\pm 0.7 \%$	$\pm 0.5\%$
Probe Positioning	$\pm 4.7\%$	R	$\sqrt{3}$	1	0.67	$\pm 2.7\%$	$\pm 1.8\%$
Extrap. and Interpolation	$\pm 1.0\%$	R	$\sqrt{3}$	1	1	$\pm 0.6\%$	$\pm 0.6\%$
Test Sample Related							
Device Positioning Vertical	$\pm 4.7\%$	R	$\sqrt{3}$	1	0.67	$\pm 2.7\%$	$\pm 1.8\%$
Device Positioning Lateral	$\pm 1.0\%$	R	$\sqrt{3}$	1	1	$\pm 0.6\%$	$\pm 0.6\%$
Device Holder and Phantom	$\pm 2.4\%$	R	$\sqrt{3}$	1	1	$\pm 1.4\%$	$\pm 1.4\%$
Power Drift	$\pm 5.0\%$	R	$\sqrt{3}$	1	1	$\pm 2.9\%$	$\pm 2.9\%$
Phantom and Setup Related							
Phantom Thickness ±2.4 %		R	$\sqrt{3}$	1	0.67	$\pm 1.4\%$	$\pm 0.9\%$
Combined Std. Uncertainty						$\pm 14.7\%$	$\pm 10.9\%$
Expanded Std. Uncertainty on Power						$\pm 29.4\%$	$\pm 21.8\%$
Expanded Std. Uncertainty on Field						$\pm 14.7\%$	$\pm 10.9\%$

Table 7.1. Worst-Case uncertainty budget for HAC free field assessment according to ANSI C63.19.

[1] The budget is valid for the frequency range 800 MHz - 3 GHz and represents a worst-case analysis.



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7.1 Site-Specific Uncertainty

RF Reflections

Section 4.2 of ANSI C63.19 requires that any RF reflecting objects are a minimum distance of 2 wavelengths away from the WD under test. For this WD, the longest wavelength occurs when the WD is transmitting at 824.7MHz. The wavelength is:

$$\lambda = \frac{c}{f} = \frac{3 \cdot 10^8 \, m/s}{824.7 \, MHz} = 0.364 \, m$$

Therefore, 2 wavelengths result in a distance of 0.73m. Tests are performed in an RF shielded chamber. The distance to the nearest wall is > 1m and the distance to the robot's safety guardrail is ~ 1.0 m, both satisfying the requirement. In addition, RF absorbing cones are placed at the base of the robot to further reduce reflections. The HAC phantom arch is made of low dielectric constant plastic and should not be a source of reflections.

Environmental Conditions

During measurements, the temperature of the test lab was kept between 21°C and 25°C and relative humidity was maintained between 20% and 55%.

Ambient Noise

ANSI C63.19 standard requires RF ambient noise to be at least 20dB below the measurement level. Scans of RF ambient noise fields were previously performed for verification and was determined to be < 20 dB than the measured WD RF field levels.